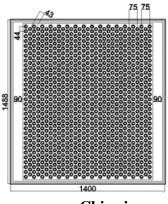


Model No. VCC-94A4WH

Features:

- 940nm VCSEL chip
- Typical 4W peak pulse output at 4.7A
- High PCE (Power Conversion Efficiency): 40%
- -20 to 85 °C operating temperature
- Number of emitters: 977
- Chip size: $1400 \times 1488 \pm 15 \mu m$
- Electrode Side: Gold alloy on both anode P (emission side) and cathode N (backside)



Chip size

Applications:

- Sensing light source
- Optical encoders
- Photoelectric sensors
- 3D sensing
- 3D imaging including Time of Flight, Structure light, Iris/ Facial recognition etc.

Absolute Maximum Ratings (TA = 25°C unless otherwise noted)

Parameter	Symbol	Rating
Storage Temperature	Tstg	-40 to 85 °C
Operating Temperature	Тор	-20 to 85 °C
Continuous Forward Current	lf	4.8A
Maximum package SMT solder reflow Temperature		260°C, 10 seconds

Note: The maximum CW laser current in the Absolute Maximum Ratings is valid for the operating temperature noted at the table above. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.

Electro-Optics Characteristics (Ta=25°C unless otherwise noted)

Parameters	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Threshold Current	Ith	-	800	-	mA	
Slope Efficiency	η	0.85	1.0	-	W/A	If = 4.7A
Optical Output Power	P₀		4000	-	mW	If = 4.7A
Center Wavelength	λς	930	940	950	nm	If = 4.7A
Beam Divergence	Θ		27		degree	Full Width 1/e ²
Operating Voltage	Vf	1.7	2.1	2.3	V	If = 4.7A
Power Conversion Efficiency	PCE		40		%	If = 4.7A
Wavelength Shift	Δλ/ΔΤ	-	0.07	-	nm/°C	If = 4.7A

Note 1: Forward Voltage (V_i) measurement allowance is $\pm 0.1V$.

Note 2: Center Wavelength (λ_c) measurement allowance is ± 1.5 nm.

Note 3: Others measurement allowance is ±10%.

Note 4: Test DUTs are mounted on star board and measured with operating bias current @ 4.7A, Duty Cycle:1%.

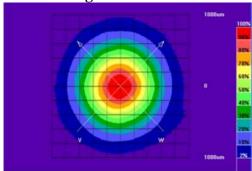
Note: The specifications are subject to change without notice.

19608 Camino De Rosa, Walnut, CA 91789, USA

Tel: (909)718-0999 e-mail: info@lasermate.com URL: http://www.lasermate.com/ Fax: (909)718-0998

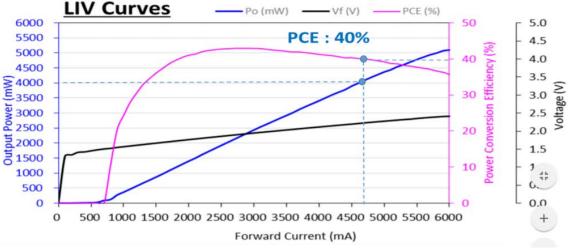
Typical Performance Graph:

Beam Divergence



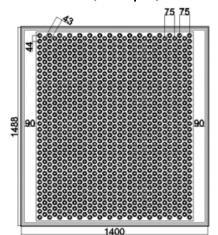
Full Width 1/e² 27 degree

LIV Graph at 25 °C



Note: Curves measurement at $0 \sim 6A$ current sweep with 1% duty cycle.

Dimensions (unit: µm):



Specification	Min	Тур	Max
Chip width	1385	1400	1415
Chip length	1473	1488	1503
Chip thickness	105	120	135
Bond pad width	-	90	-

Unit: µm

Tel: (909)718-0999

Fax: (909)718-0998

Note: 1. Allowable abnormal aperture is 1%.

2. Continuous abnormal aperture (x, y or diagonal direction) is not allowed.

Note: The specifications are subject to change without notice.

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